



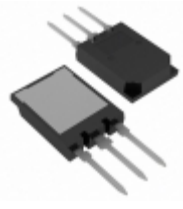




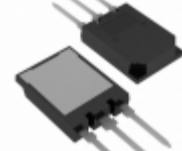


	<h2 style="color: red;">SIHP8N50D-E3</h2>
	Hersteller-Teilenummer: SIHP8N50D-E3
	Hersteller / Marke: Vishay / Siliconix
	Teil der Beschreibung: MOSFET N-CH 500V 8.7A TO220AB
	Datenblätter: <ul style="list-style-type: none">  1.SIHP8N50D-E3.pdf  2.SIHP8N50D-E3.pdf  3.SIHP8N50D-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 5000 pcs Stock Available.
	Lieferr von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIHP8N50D-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 500V 8.7A TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	156W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.7A (Tc)
Rds On (Max) @ Id, Vgs	850 mOhm @ 4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	527pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube


















































SIHP8N50D-E3 ist neu im Original, Suche SIHP8N50D-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHP8N50D-E3 Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage SIHP8N50D-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIHS20N50C-E3 Vishay / Siliconix MOSFET N-CH 500V 20A TO-247AD</p>	 <p>SIHP8N50D-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 8.7A TO220AB</p>	 <p>SIHP8N50D Vishay Vishay TO-220AB</p>	 <p>SIHP7N60E-GE3 Vishay / Siliconix MOSFET N-CH 600V 7A TO-220AB</p>
 <p>SIHP7N60E-E3 Vishay / Siliconix MOSFET N-CH 600V 7A TO-220AB</p>	 <p>SIHS20N50C-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 20A TO-247AD</p>	 <p>SIHP8N50D-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 8.7A TO220AB</p>	 <p>SIHP7N60E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 7A TO-220AB</p>

heiße Teile

Mehr

 SIHFSL11N50A	 SIHG16N50C-E3	 SIHG16N50C-E3	 SIHG17N60D	 SIHG20N50C
 SIHG22N60S-E3	 SIHG30N60E	 SIHG33N60E	 SIHG47N60E-E3	 SIHG47N60E-E3
 SIHG47N60E-GE3	 SIHG47N60E-GE3	 SIHG47N60S-E3	 SIHG70N60EFEF-GE3	 SIHG73N60E-GE3
 SIHG73N60E-GE3	 SIHP10N40D	 SIHP12N50C-E3	 SIHP12N50C-E3	 SIHP12N60E-E3
 SIHP12N60E-E3	 SIHP12N60E-GE3	 SIHP12N60E-GE3	 SIHP12N65E	 SIHP14N50D
 SIHP15N60E-E3	 SIHP15N60E-E3	 SIHP15N65E	 SIHP16N50C-E3	 SIHP16N50C-E3
 SIHP17N60D-E3	 SIHP17N60D-E3	 SIHP18N50C-E3	 SIHP18N50C-E3	 SIHP22N60S-E3
 SIHP30N60E-E3	 SIHP30N60E-E3	 SIHP30N60E-GE3	 SIHP30N60E-GE3	 SIHP30N60E-GE3
 SIHP33N60E-GE3	 SIHP33N60E-GE3	 SIHP5N50D-E3	 SIHP5N50D-E3	 SIHP6N40D
 SIHP8N50D-E3	 SIHU3N50D-E3	 SIHU3N50D-E3	 SIHW30N60E-GE3	 SIHW30N60E-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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